TOSHIBA Photocoupler IRED & Photo-IC

# **TLP109**

### Programmable Controllers Industrial Inverters Switching Power Supplies

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The Toshiba TLP109 mini-flat coupler is a small-outline coupler suitable for surface-mount assembly. The TLP109 consists of a high-output-power infrared LED optically coupled to a high-speed photodiode-transistor chip.

The TLP109 is housed in the SO6 package and guarantees a creepage distance of  $\geq 5.0$  mm, a clearance of  $\geq 5.0$  mm and an insulation thickness of  $\geq 0.4$  mm. Therefore, the TLP109 meets the reinforced insulation class requirements of international safety standards.

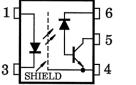
- •Isolation voltage: 3750 Vrms (min)
- •Switching speed:  $t_{pHL} = 0.8 \ \mu s$ ,  $t_{pLH} = 0.8 \ \mu s$  (max)
  - $@R_L = 1.9 \text{ k}\Omega$
- $\bullet TTL\text{-}compatible$
- •UL-recognized : UL 1577, File No.E67349
- •cUL-recognized : CSA Component Acceptance Service No.5A File No.E67349
- •VDE-approved: EN 60747-5-5, EN 62368-1 (Note 1)

•CQC-approved: GB4943.1, GB8898 Thailand Factory

COC 仅适用干海拔 2000m 以下地区安全使用

Note 1 : When a VDE approved type is needed, please designate the **Option(V4)**.

## Pin Configuration (Top View)



1: ANODE 3: CATHODE 4: EMITTER (GND) 5: COLLECTOR (OUTPUT) 6: V<sub>CC</sub>

**Construction Mechanical Ratings** 

Creepage distance:	5.0 mm (min)
Clearance:	5.0 mm (min)
Insulation thickness:	0.4 mm (min)



55

0.4

2.1 ± 0. \_\_\_\_0.15

...

3.7 + 0.25 3.7 - 0.15

1.27

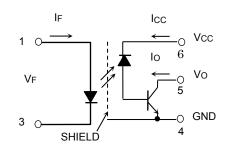
Weight: 0.08 g (typ.)

2.54

JEDEC

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JEITA



2019-10-10

 $7.0 \pm 0.4$ 

0.5 min

11-4L1

#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
	Forward current		lF	20	mA
	Forward Current Derating (Ta ≥ 95 °C)		ΔIF/°C	-0.36	mA/°C
ED	Pulse forward current	(Note 1)	IFP	40	mA
Щ	Peak transient forward current	(Note 2)	IFPT	1	А
	Reverse voltage		VR	5	V
	Power dissipation	(Note 3)	PD	40	mW
	Output current		lo	8	mA
	Output Current Derating (Ta $\ge$ 95 °C)		∆IO/°C	-0.3	mA/°C
Detector	Peak output current		IOP	16	mA
Dete	Supply voltage		Vcc	-0.5 to 30	V
	Output voltage		Vo	-0.5 to 20	V
	Output power dissipation	(Note 4)	Po	100	mW
Ope	Operating temperature range		Topr	-55 to 125	°C
Sto	Storage temperature range		Tstg	-55 to 125	°C
Lea	Lead solder temperature (10 s)		T <sub>sol</sub>	260	°C
	Isolation Voltage (AC, 60 s, R.H. ≤ 60 %) (No		BVs	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: 50 % duty cycle, 1 ms pulse width. Derate 0.72 mA / °C above 95 °C.
- Note 2: Pulse width  $\leq$  1 µs, 300 pps.
- Note 3: Derate 0.72 mW / °C above 95 °C.
- Note 4: Derate 1.8 mW / °C above 95 °C.
- Note 5: Device considered a two-terminal device: Pins 1 and 3 shorted together, and pins 4, 5 and 6 shorted together.

## **Electrical Characteristics (Ta = 25°C)**

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I <sub>F</sub> = 16 mA	1.50	1.64	1.85	V
	Forward voltage temperature coefficient	ΔV <sub>F</sub> / ΔTa	IF = 16 mA		-1.6	_	mV /°C
LED	Reverse current	IR	V <sub>R</sub> = 3 V		Ι	10	μA
	Capacitance between terminals	CT	V <sub>F</sub> = 0 V, f = 1 MHz		60	_	pF
Detector	High level output current	IOH (1)	$I_{F}$ = 0 mA, $V_{CC}$ = $V_{O}$ = 5.5 V		3	500	nA
		IOH (2)	$I_F = 0 \text{ mA}, V_{CC} = 30 \text{ V}$ $V_O = 20 \text{ V}$		-	5	
		Юн	IF = 0 mA, V <sub>CC</sub> = 30 V V <sub>O</sub> = 20 V, Ta = 100 °C			50	μA
	High level supply current	Іссн	IF = 0 mA, V <sub>CC</sub> = 30 V	_	0.01	1	μA
Current transfer ratio		IO / IF	IF = 16 mA, V <sub>CC</sub> = 4.5 V V <sub>O</sub> = 0.4 V	20	_	_	%
Low level output voltage		Vol	IF = 16 mA, V <sub>CC</sub> = 4.5 V I <sub>O</sub> = 2.4 mA	_	_	0.4	V

#### Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V = 0 V, f = 1 MHz (Note 5)	_	0.8	-	pF
Isolation resistance	Rs	R.H. ≤ 60 %, V <sub>S</sub> = 500 V (Note 5)	10 <sup>12</sup>	10 <sup>14</sup>	-	Ω
Isolation voltage	BVs	AC, 60 s (Note 5)	3750	_	_	Vrms

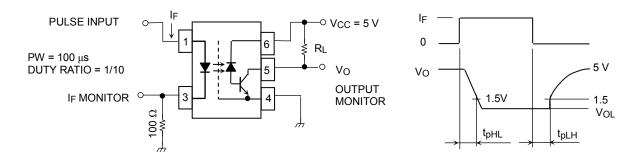
## Switching Characteristics (Ta = 25°C, Vcc = 5 V)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time ( $H \rightarrow L$ )	tpHL	Figure 1	$I_F = 0 \rightarrow 16 \text{ mA}$ $R_L = 1.9 \text{ k}\Omega$	_	_	0.8	μS
Propagation delay time (L $\rightarrow$ H)	tpLH	Figure 1	$I_F = 16 \rightarrow 0 \text{ mA}$ R <sub>L</sub> = 1.9 k $\Omega$		_	0.8	μS
Common mode transient immunity at high output level (Note 6)	CM <sub>H</sub>	Figure 2	IF = 0 mA, V <sub>CM</sub> = 400 V <sub>p-p</sub> R <sub>L</sub> = 4.1 kΩ	5000	10000	_	V / μs
Common mode transient Immunity at low output level (Note 6)	CML	Figure 2	I <sub>F</sub> = 16 mA, V <sub>CM</sub> = 400 V <sub>p-p</sub> R <sub>L</sub> = 4.1 kΩ	-5000	-10000		V / μs

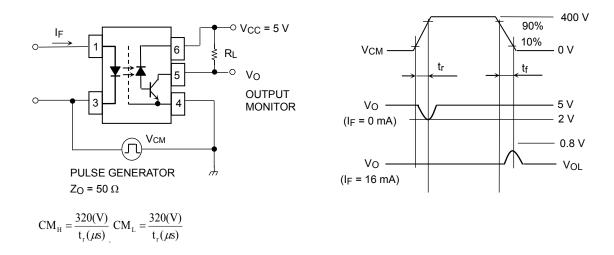
Note 6:  $CM_L$  is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state (VO < 0.8 V).  $CM_H$  is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state (VO > 2.0 V)

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## Figure 1: Switching Time Test Circuit and Waveform

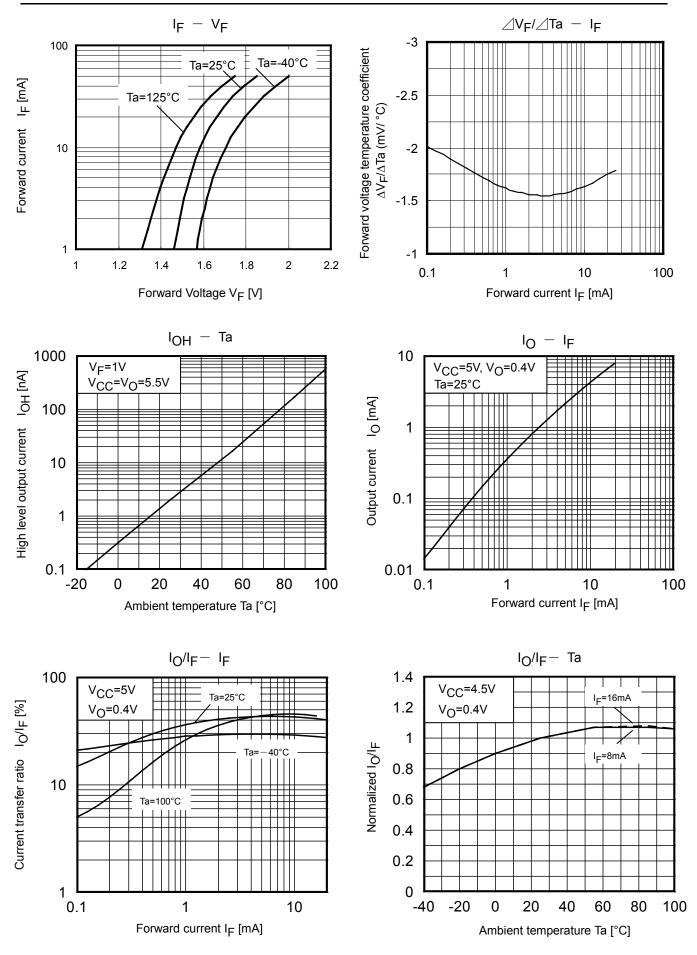






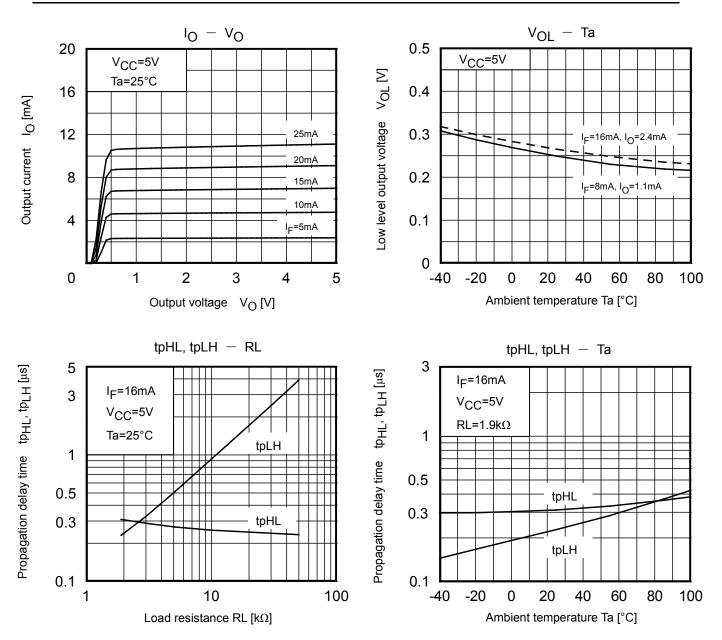
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**TLP109** 



NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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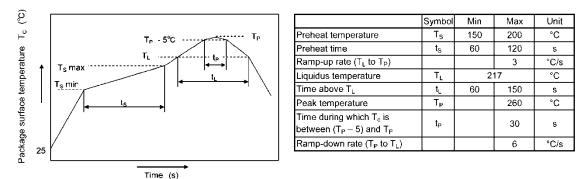
# PRECAUTIONS OF SURFACE MOUNTING TYPE PHOTOCOUPLER SOLDERING & GENERAL STORAGE

## (1) Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

1) When Using Soldering Reflow

An example of a temperature profile when lead(Pb)-free solder is used



• The soldering temperature profile is based on the package surface temperature (See the figure shown below, which is based on the package surface temperature.)

• Reflow soldering must be performed once or twice.

• The mounting should be completed with the interval from the first to the last mountings being 2 weeks..

2) When using soldering Flow

- Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds.
- Mounting condition of 260 °C within 10 seconds is recommended.
- Flow soldering must be performed once.

3) When using soldering Iron

• Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C.

• Heating by soldering iron must be only once per 1 lead

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